



Vincotech

# 10-PY07NPA150SM02-L365F08Y

datasheet

flowNPC 1

1200 V / 150 A

## Features

- NPC inverter topology
- Optimized for full rated bi-directional usage (4quadrant)
- Optimized for 1200 Vdc applications
- High-speed IGBT in all switch positions
- Integrated NTC
- Low inductive design with integrated DC capacitor
- flow 1 12mm package

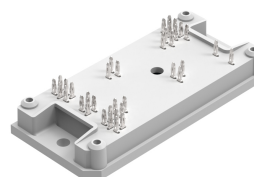
## Target applications

- Energy Storage Systems
- Solar Inverters
- UPS

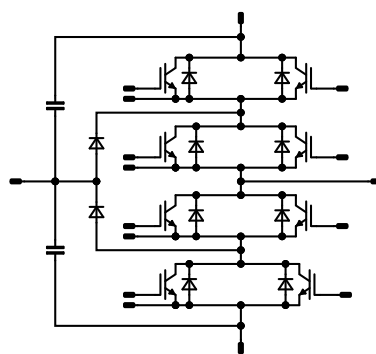
## Types

- 10-PY07NPA150SM02-L365F08Y

## flow 1 12 mm housing



## Schematic





Vincotech

**10-PY07NPA150SM02-L365F08Y**  
datasheet

## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
-----------	--------	------------	-------	------

### Buck Switch

Collector-emitter voltage	$V_{CES}$		650	V
Collector current (DC current)	$I_C$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	83	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	450	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	128	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Maximum junction temperature	$T_{jmax}$		175	°C

### Buck Diode

Peak repetitive reverse voltage	$V_{RRM}$		650	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	86	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	300	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	113	W
Maximum junction temperature	$T_{jmax}$		175	°C

### Boost Switch

Collector-emitter voltage	$V_{CES}$		650	V
Collector current (DC current)	$I_C$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	83	A
Repetitive peak collector current	$I_{CRM}$	$t_p$ limited by $T_{jmax}$	450	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	128	W
Gate-emitter voltage	$V_{GES}$		$\pm 20$	V
Maximum junction temperature	$T_{jmax}$		175	°C



Vincotech

## Maximum Ratings

$T_j = 25\text{ °C}$ , unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
<b>Boost Diode</b>				
Peak repetitive reverse voltage	$V_{RRM}$		650	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	86	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	300	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	113	W
Maximum junction temperature	$T_{jmax}$		175	°C

## Boost Sw. Inv. Diode

Peak repetitive reverse voltage	$V_{RRM}$		650	V
Forward current (DC current)	$I_F$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	108	A
Repetitive peak forward current	$I_{FRM}$	$t_p$ limited by $T_{jmax}$	300	A
Total power dissipation	$P_{tot}$	$T_j = T_{jmax}$ $T_s = 80\text{ °C}$	149	W
Maximum junction temperature	$T_{jmax}$		175	°C

## Capacitor (DC)

Maximum DC voltage	$V_{MAX}$		630	V
Operation Temperature	$T_{op}$		-55 ... 125	°C

## Module Properties

### Thermal Properties

Storage temperature	$T_{stg}$		-40...+125	°C
Operation temperature under switching condition	$T_{jop}$		-40...+( $T_{jmax} - 25$ )	°C

### Isolation Properties

Isolation voltage	$V_{isol}$	DC Test Voltage* $t_p = 2\text{ s}$	6000	V
Isolation voltage	$V_{isol}$	AC Voltage $t_p = 1\text{ min}$	2500	V
Creepage distance			>12,7	mm
Clearance			7,86	mm
Comparative Tracking Index	CTI		≥ 200	

\*100 % tested in production



Vincotech

## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Buck Switch

#### Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0015	25	3,3	4	4,7	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		150	25 125 150		1,7 1,89 1,94	2,22 <sup>(1)</sup>	V
Collector-emitter cut-off current	$I_{CES}$		0	650		25			80	μA
Gate-emitter leakage current	$I_{GES}$		20	0		25			240	nA
Internal gate resistance	$r_g$							None		Ω
Input capacitance	$C_{ies}$	$f = 1 \text{ Mhz}$	0	25		25		8600		pF
Output capacitance	$C_{oes}$							150		pF
Reverse transfer capacitance	$C_{res}$							32		pF
Gate charge	$Q_g$	$V_{CC} = 520 \text{ V}$	15		150	25		332		nC

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,74		K/W
--	---------------	---	--	--	--	--	--	------	--	-----

#### Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \text{ } \Omega$ $R_{goff} = 2 \text{ } \Omega$	-5/15	350	90	25 125 150		47,6 46,2 45,6		ns
Rise time	$t_r$					25 125 150		10,6 12,2 13,2		ns
Turn-off delay time	$t_{d(off)}$					25 125 150		133,4 151,8 156,2		ns
Fall time	$t_f$					25 125 150		7,04 7,09 7,7		ns
Turn-on energy (per pulse)	$E_{on}$	$Q_{tFWD} = 3,8 \text{ } \mu\text{C}$ $Q_{tFWD} = 7,08 \text{ } \mu\text{C}$ $Q_{tFWD} = 8,09 \text{ } \mu\text{C}$				25 125 150		0,737 1,12 1,21		mWs
Turn-off energy (per pulse)	$E_{off}$					25 125 150		0,367 0,706 0,798		mWs





Vincotech

# 10-PY07NPA150SM02-L365F08Y

datasheet

## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Buck Diode

#### Static

Forward voltage	$V_F$				150	25 125 150		1,67 1,66 1,66	1,92 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_i = 650$ V				25			7,6	µA

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						0,84		K/W
--	---------------	---------------------------------------	--	--	--	--	--	------	--	-----

#### Dynamic

Peak recovery current	$I_{RRM}$	$di/dt=7000$ A/µs $di/dt=7124$ A/µs $di/dt=6971$ A/µs	-5/15	350	90	25 125 150		110,05 143,32 151,37		A
Reverse recovery time	$t_{rr}$					25 125 150		52,28 84,92 95,83		ns
Recovered charge	$Q_r$					25 125 150		3,8 7,08 8,09		µC
Reverse recovered energy	$E_{rec}$					25 125 150		0,853 1,61 1,85		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		2642 2119 2131		A/µs



Vincotech

## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Boost Switch

#### Static

Gate-emitter threshold voltage	$V_{GE(th)}$	$V_{CE} = V_{GE}$			0,0015	25	3,3	4	4,7	V
Collector-emitter saturation voltage	$V_{CE(sat)}$		15		150	25 125 150		1,7 1,89 1,94	2,22 <sup>(1)</sup>	V
Collector-emitter cut-off current	$I_{CES}$		0	650		25			80	µA
Gate-emitter leakage current	$I_{GES}$		20	0		25			240	nA
Internal gate resistance	$r_g$							None		Ω
Input capacitance	$C_{ies}$	$f = 1 \text{ Mhz}$	0	25		25		8600		pF
Output capacitance	$C_{oes}$							150		pF
Reverse transfer capacitance	$C_{res}$							32		pF
Gate charge	$Q_g$	$V_{CC} = 520 \text{ V}$	15		150	25		332		nC

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						0,74		K/W
--	---------------	---	--	--	--	--	--	------	--	-----

#### Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 2 \text{ } \Omega$ $R_{goff} = 2 \text{ } \Omega$	-5/15	350	90	25 125 150		50,2 50,6 50		ns
Rise time	$t_r$					25 125 150		11,2 13,4 14		ns
Turn-off delay time	$t_{d(off)}$					25 125 150		114,2 134,4 138,6		ns
Fall time	$t_f$					25 125 150		5,07 7,41 8,47		ns
Turn-on energy (per pulse)	$E_{on}$					25 125 150		1,1 1,77 1,92		mWs
Turn-off energy (per pulse)	$E_{off}$					25 125 150		0,243 0,621 0,719		mWs



Vincotech

# 10-PY07NPA150SM02-L365F08Y

datasheet

## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
			$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]	Min	Typ	Max	

### Boost Diode

#### Static

Forward voltage	$V_F$				150	25 125 150		1,67 1,66 1,66	1,92 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_i = 650$ V				25			7,6	µA

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						0,84		K/W
--	---------------	---------------------------------------	--	--	--	--	--	------	--	-----

#### Dynamic

Peak recovery current	$I_{RRM}$	$di/dt=5600$ A/µs $di/dt=6000$ A/µs $di/dt=5796$ A/µs	-5/15	350	90	25 125 150		89,81 116,5 121,4		A
Reverse recovery time	$t_{rr}$					25 125 150		60,9 97,24 109,23		ns
Recovered charge	$Q_r$					25 125 150		3,6 6,94 7,94		µC
Reverse recovered energy	$E_{rec}$					25 125 150		0,692 1,33 1,53		mWs
Peak rate of fall of recovery current	$(di_{rr}/dt)_{max}$					25 125 150		1618 1020 864,39		A/µs



Vincotech

## Characteristic Values

Parameter	Symbol	Conditions					Values			Unit
		$V_{GE}$ [V] $V_{GS}$ [V]	$V_{CE}$ [V] $V_{DS}$ [V] $V_F$ [V]	$I_C$ [A] $I_D$ [A] $I_F$ [A]	$T_j$ [°C]		Min	Typ	Max	

### Boost Sw. Inv. Diode

#### Static

Forward voltage	$V_F$			150	25 125 150		1,18	1,66 1,61 1,59	1,82 <sup>(1)</sup>	V
Reverse leakage current	$I_R$	$V_i = 650$ V			25				1,8	µA

#### Thermal

Thermal resistance junction to sink <sup>(2)</sup>	$R_{th(j-s)}$	$\lambda_{paste} = 3,4$ W/mK (PSX)						0,64		K/W
--	---------------	------------------------------------	--	--	--	--	--	------	--	-----

### Capacitor (DC)

#### Static

Capacitance	$C$	DC bias voltage = 0 V			25			300		nF
Tolerance						-10			10	%
Dissipation factor		$f = 1$ kHz			25			2,5		%

### Thermistor

#### Static

Rated resistance	$R$				25			22		kΩ
Deviation of $R_{100}$	$\Delta R/R$	$R_{100} = 1484$ Ω			100	-5			5	%
Power dissipation	$P$							5		mW
Power dissipation constant	$d$				25			1,5		mW/K
B-value	$B_{(25/50)}$	Tol. $\pm 1$ %						3962		K
B-value	$B_{(25/100)}$	Tol. $\pm 1$ %						4000		K
Vincotech Thermistor Reference									I	

<sup>(1)</sup> Value at chip level

<sup>(2)</sup> Only valid with pre-applied Vincotech thermal interface material.



Vincotech

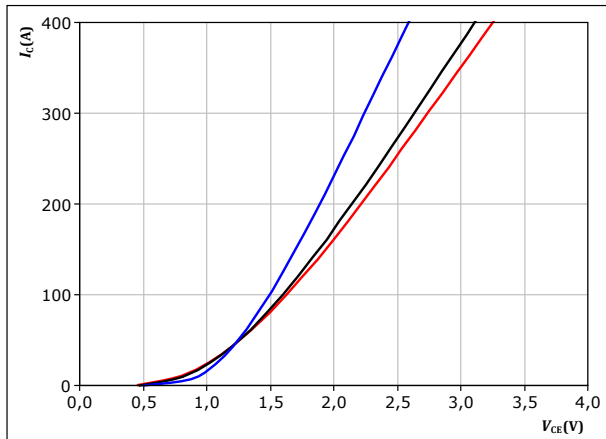
# 10-PY07NPA150SM02-L365F08Y datasheet

## Buck Switch Characteristics

figure 1. IGBT

Typical output characteristics

$$I_c = f(V_{CE})$$

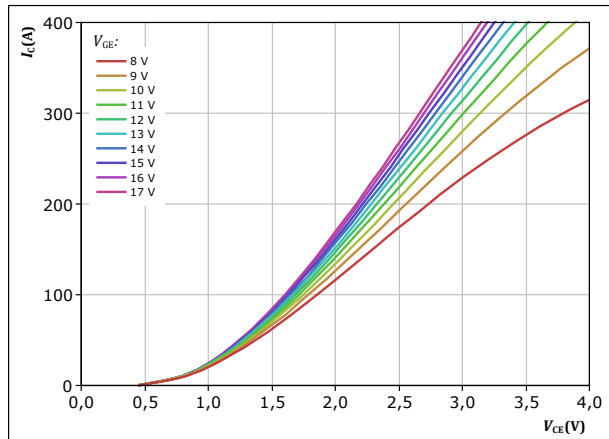


$t_p = 250 \mu s$   
 $V_{GE} = 15 V$   
 $T_j:$  25 °C, 125 °C, 150 °C

figure 2. IGBT

Typical output characteristics

$$I_c = f(V_{CE})$$

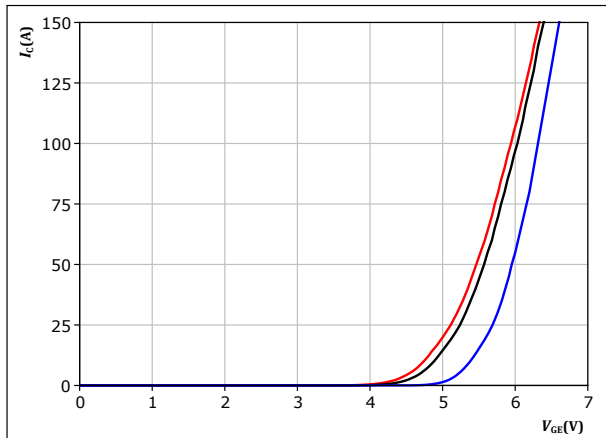


$t_p = 250 \mu s$   
 $T_j = 150 ^\circ C$   
 $V_{GE}$  from 8 V to 17 V in steps of 1 V

figure 3. IGBT

Typical transfer characteristics

$$I_c = f(V_{GE})$$

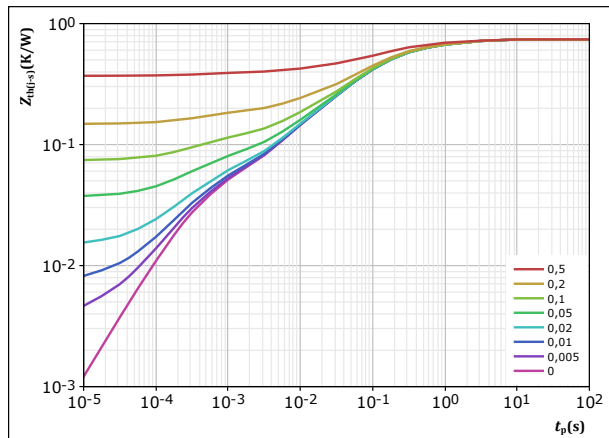


$t_p = 250 \mu s$   
 $V_{CE} = 10 V$   
 $T_j:$  25 °C, 125 °C, 150 °C

figure 4. IGBT

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$   
 $R_{th(j-s)} = 0,74 K/W$   
IGBT thermal model values  

$R (K/W)$	$\tau (s)$
1,09E-01	1,94E+00
2,21E-01	2,60E-01
2,87E-01	6,98E-02
8,43E-02	8,29E-03
3,94E-02	3,67E-04



Vincotech

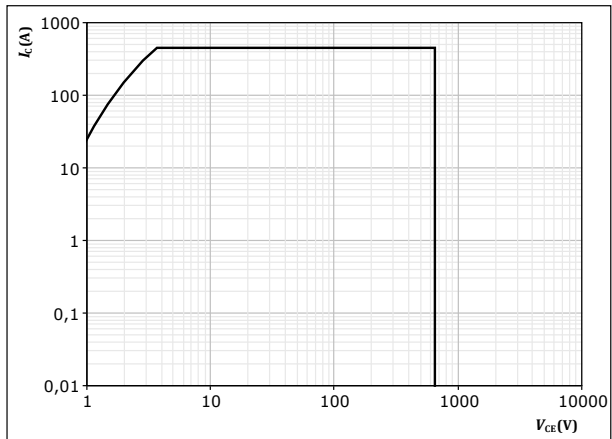
**10-PY07NPA150SM02-L365F08Y**  
datasheet

## Buck Switch Characteristics

**figure 5.** IGBT

Safe operating area

$$I_C = f(V_{CE})$$



$D =$  single pulse

$T_s = 80 \text{ } ^\circ\text{C}$   
 $V_{GE} = 15 \text{ V}$   
 $T_j = T_{jmax}$



Vincotech

# 10-PY07NPA150SM02-L365F08Y

datasheet

## Buck Diode Characteristics

figure 6. FWD

Typical forward characteristics

$$I_F = f(V_F)$$

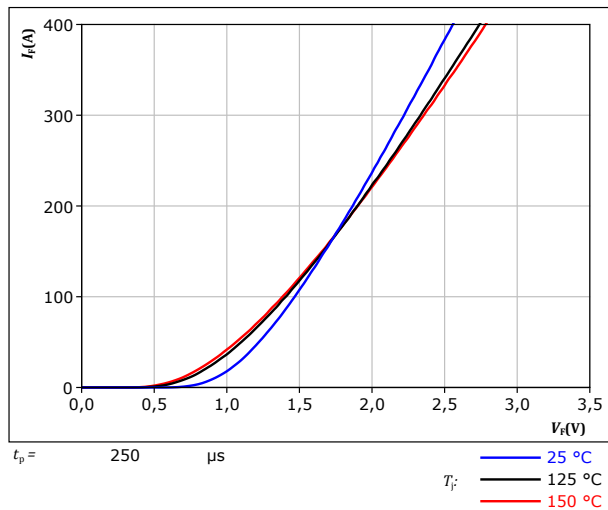
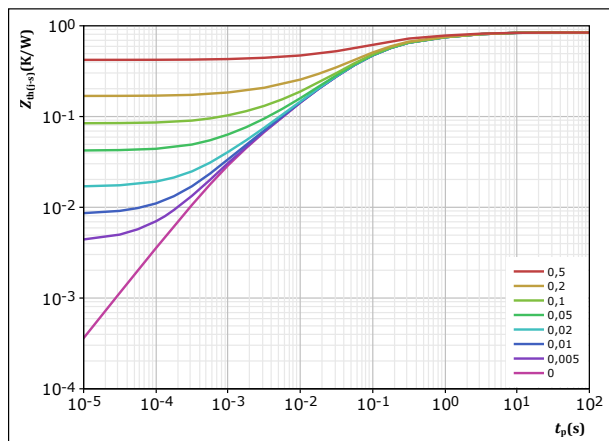


figure 7. FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D =$	$t_p / T$
$R_{th(j-s)} =$	0,843 K/W
FWD thermal model values	
$R$ (K/W)	$\tau$ (s)
6,09E-02	4,33E+00
1,45E-01	8,74E-01
3,25E-01	1,39E-01
2,06E-01	4,67E-02
8,27E-02	9,15E-03
2,35E-02	1,16E-03



Vincotech

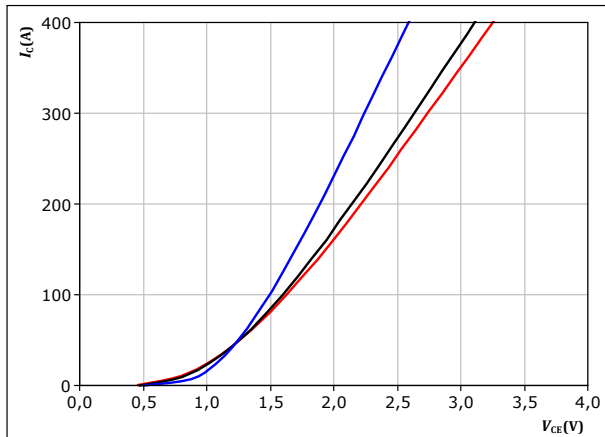
# 10-PY07NPA150SM02-L365F08Y datasheet

## Boost Switch Characteristics

figure 8. IGBT

Typical output characteristics

$$I_c = f(V_{CE})$$



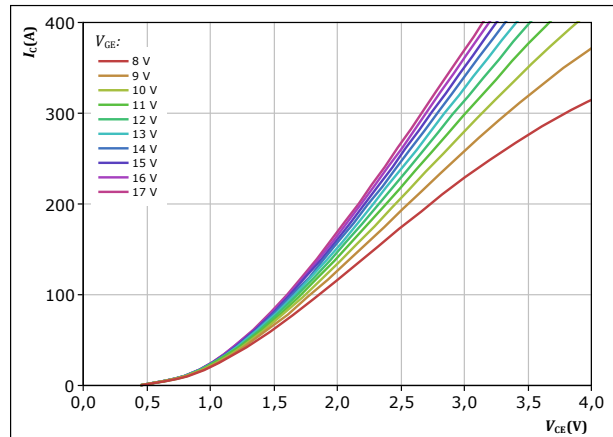
$t_p = 250 \mu s$   
 $V_{GE} = 15 V$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 9. IGBT

Typical output characteristics

$$I_c = f(V_{CE})$$

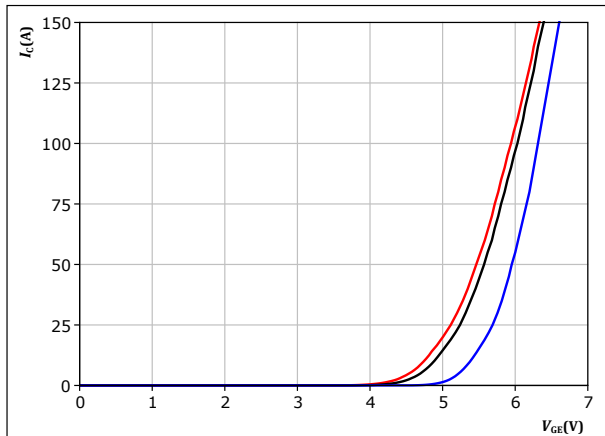


$t_p = 250 \mu s$   
 $T_j = 150 ^\circ C$   
 $V_{GE}$  from 8 V to 17 V in steps of 1 V

figure 10. IGBT

Typical transfer characteristics

$$I_c = f(V_{GE})$$



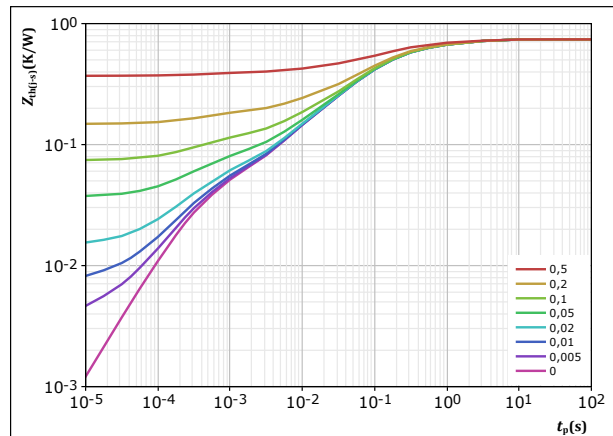
$t_p = 250 \mu s$   
 $V_{CE} = 10 V$

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 11. IGBT

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D = t_p / T$   
 $R_{th(j-s)} = 0,74 K/W$   
IGBT thermal model values  

$R (K/W)$	$\tau (s)$
1,09E-01	1,94E+00
2,21E-01	2,60E-01
2,87E-01	6,98E-02
8,43E-02	8,29E-03
3,94E-02	3,67E-04





Vincotech

**10-PY07NPA150SM02-L365F08Y**  
datasheet

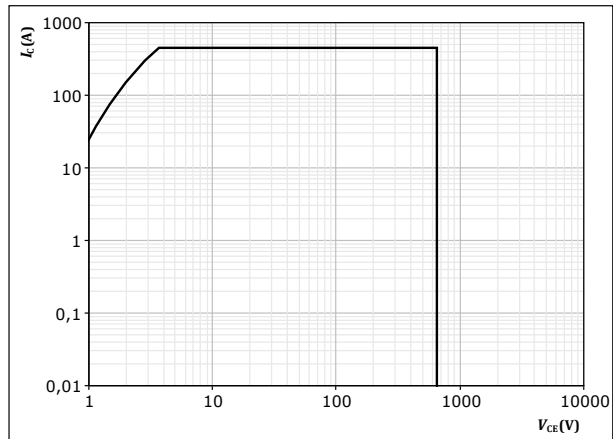
## Boost Switch Characteristics

figure 12.

IGBT

Safe operating area

$I_C = f(V_{CE})$



$D = \text{single pulse}$

$T_s = 80 \text{ } ^\circ\text{C}$   
 $V_{GE} = 15 \text{ V}$   
 $T_j = T_{jmax}$



Vincotech

# 10-PY07NPA150SM02-L365F08Y

datasheet

## Boost Diode Characteristics

figure 13.

FWD

Typical forward characteristics

$$I_F = f(V_F)$$

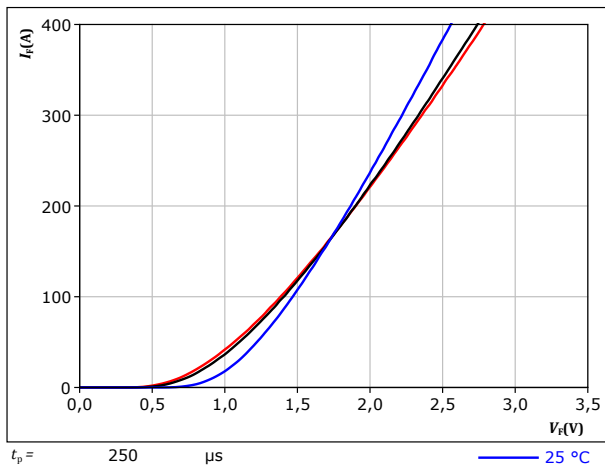
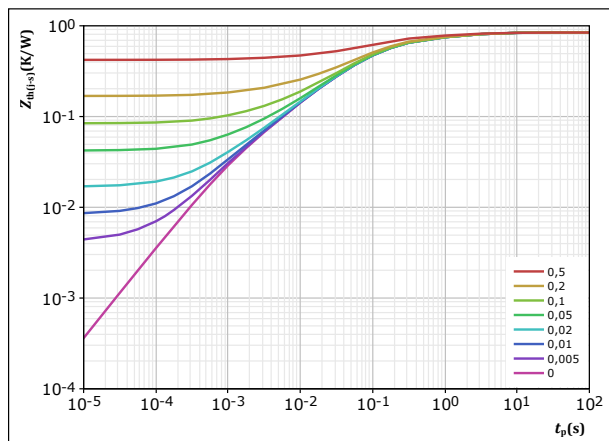


figure 14.

FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D =$	$t_p / T$
$R_{th(j-s)} =$	0,843 K/W
FWD thermal model values	
$R$ (K/W)	$\tau$ (s)
6,09E-02	4,33E+00
1,45E-01	8,74E-01
3,25E-01	1,39E-01
2,06E-01	4,67E-02
8,27E-02	9,15E-03
2,35E-02	1,16E-03



Vincotech

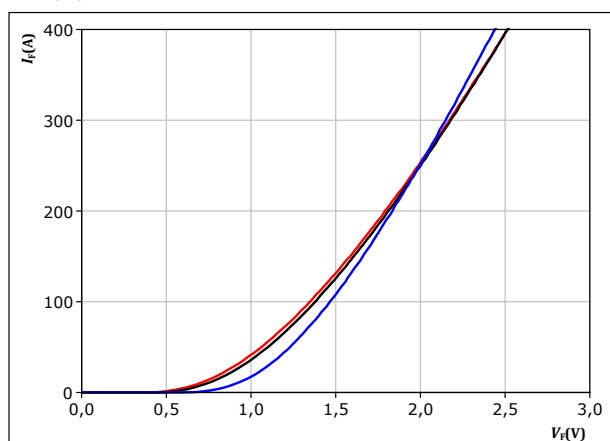
## Boost Sw. Inv. Diode Characteristics

figure 15.

FWD

Typical forward characteristics

$$I_F = f(V_F)$$



$t_p = 250 \mu s$

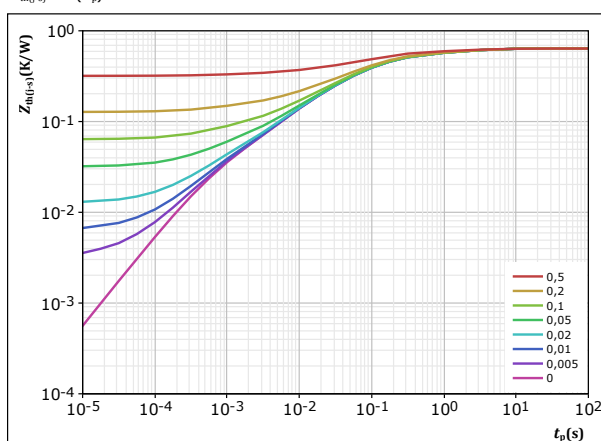
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 16.

FWD

Transient thermal impedance as a function of pulse width

$$Z_{th(j-s)} = f(t_p)$$



$D =$	$t_p / T$	
$R_{th(j-s)} =$	0,638	K/W
FWD thermal model values		
$R$ (K/W)	$\tau$ (s)	
6,14E-02	3,48E+00	
1,03E-01	5,85E-01	
2,81E-01	9,46E-02	
1,21E-01	2,14E-02	
4,83E-02	5,07E-03	
2,26E-02	5,92E-04	



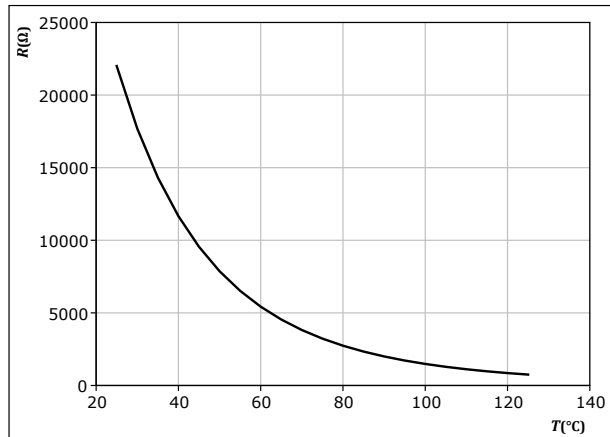
Vincotech

## Thermistor Characteristics

**figure 17.** Thermistor

Typical NTC characteristic as function of temperature

$$R_T = f(T)$$





Vincotech

# 10-PY07NPA150SM02-L365F08Y

datasheet

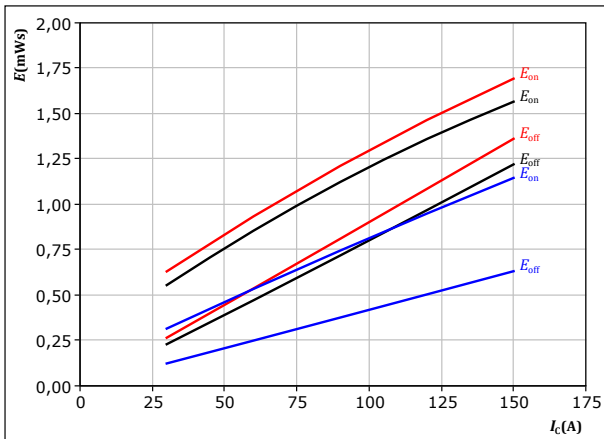
## Buck Switching Characteristics

figure 18.

IGBT

Typical switching energy losses as a function of collector current

$$E = f(I_C)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$   $\Omega$   
 $R_{goff} = 2$   $\Omega$

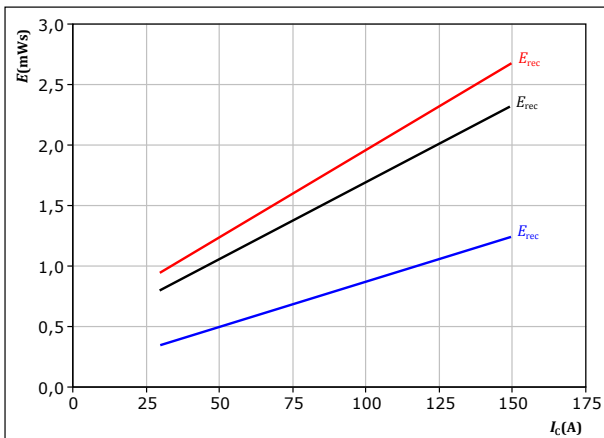
$T_j$ : 25 °C  
125 °C  
150 °C

figure 20.

FWD

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_C)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$   $\Omega$

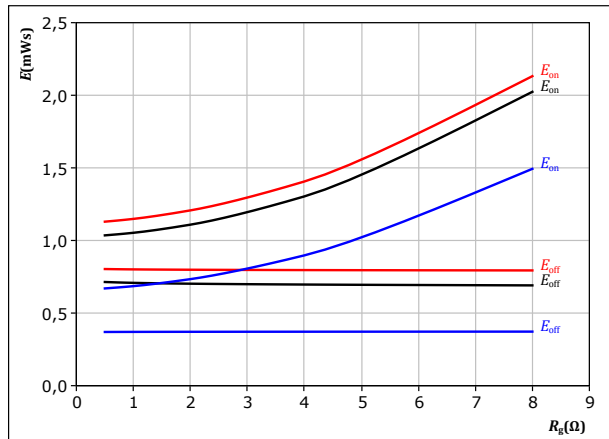
$T_j$ : 25 °C  
125 °C  
150 °C

figure 19.

IGBT

Typical switching energy losses as a function of gate resistor

$$E = f(R_g)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_C = 90$  A

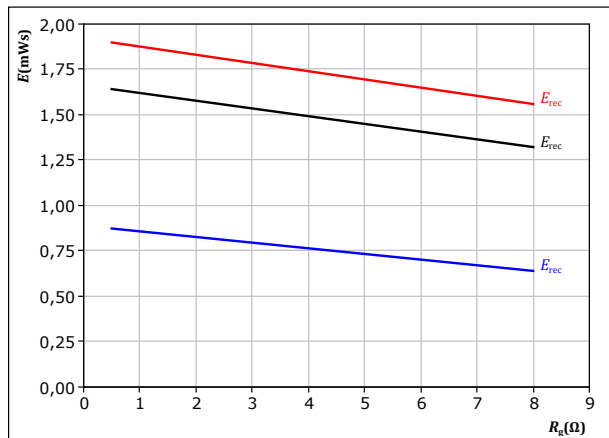
$T_j$ : 25 °C  
125 °C  
150 °C

figure 21.

FWD

Typical reverse recovered energy loss as a function of gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_C = 90$  A

$T_j$ : 25 °C  
125 °C  
150 °C



Vincotech

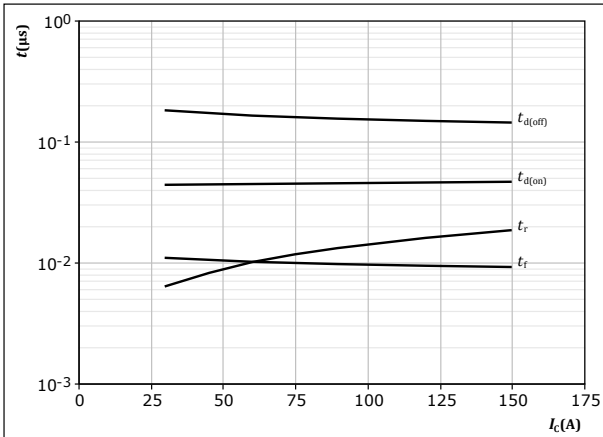
**10-PY07NPA150SM02-L365F08Y**  
datasheet

## Buck Switching Characteristics

figure 22.

IGBT

Typical switching times as a function of collector current  
 $t = f(I_C)$



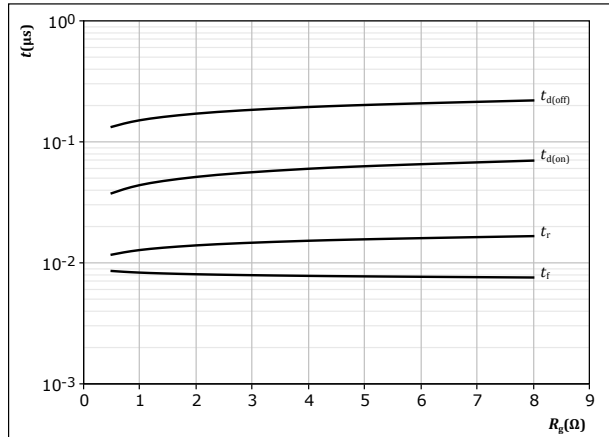
With an inductive load at

$T_j = 150$  °C  
 $V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$  Ω  
 $R_{goff} = 2$  Ω

figure 23.

IGBT

Typical switching times as a function of gate resistor  
 $t = f(R_g)$



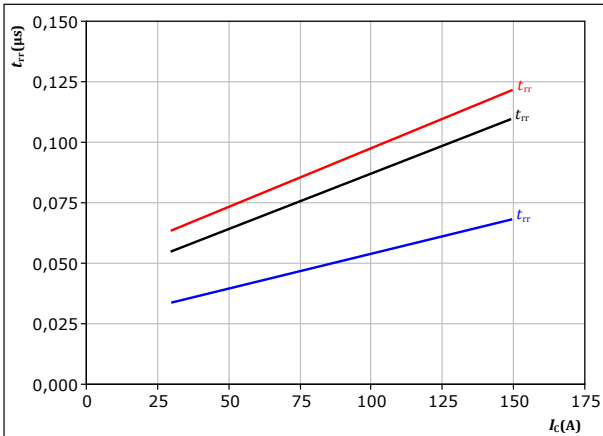
With an inductive load at

$T_j = 150$  °C  
 $V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_C = 90$  A

figure 24.

FWD

Typical reverse recovery time as a function of collector current  
 $t_{rr} = f(I_C)$



With an inductive load at

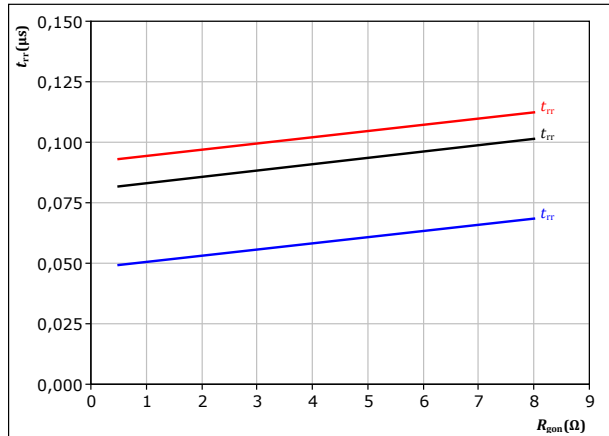
$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$  Ω

$T_j$ : — 25 °C  
— 125 °C  
— 150 °C

figure 25.

FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor  
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_C = 90$  A

$T_j$ : — 25 °C  
— 125 °C  
— 150 °C



Vincotech

10-PY07NPA150SM02-L365F08Y  
datasheet

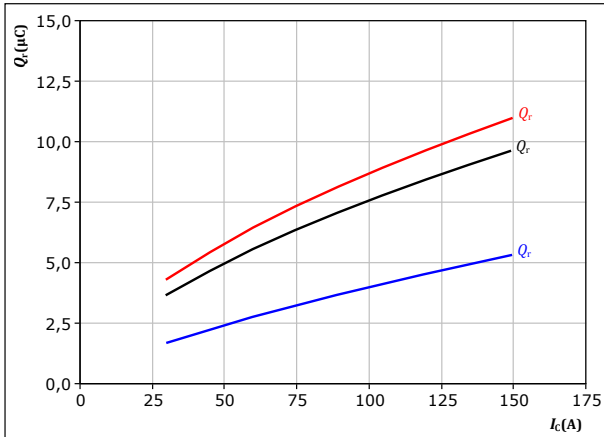
## Buck Switching Characteristics

figure 26.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$  Ω

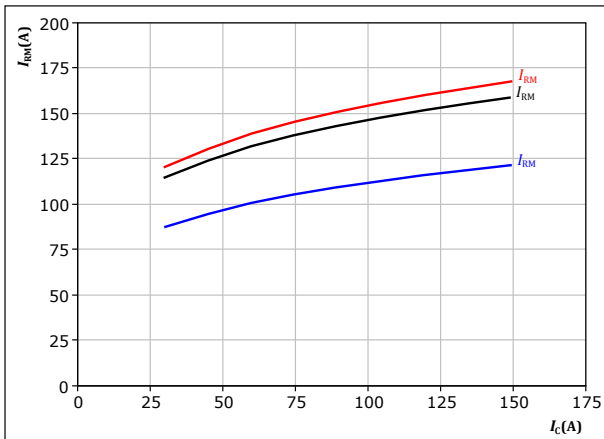
$T_j$ : 25 °C  
125 °C  
150 °C

figure 28.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$  Ω

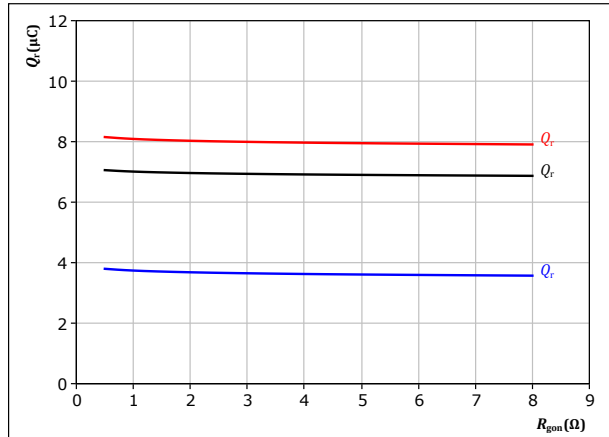
$T_j$ : 25 °C  
125 °C  
150 °C

figure 27.

FWD

Typical recovered charge as a function of turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_c = 90$  A

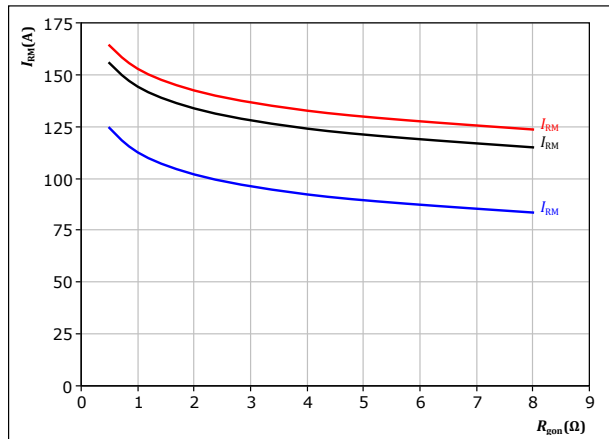
$T_j$ : 25 °C  
125 °C  
150 °C

figure 29.

FWD

Typical peak reverse recovery current as a function of turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_c = 90$  A

$T_j$ : 25 °C  
125 °C  
150 °C



Vincotech

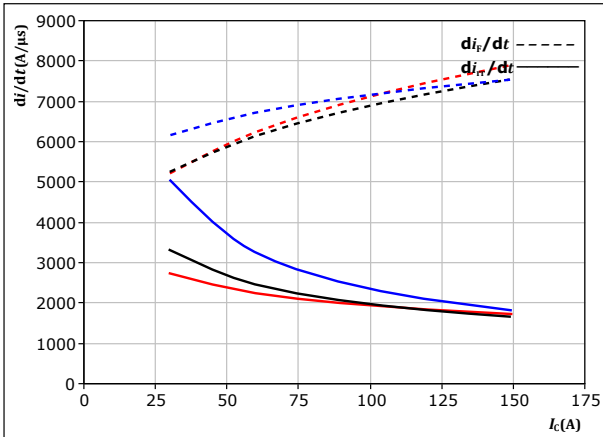
10-PY07NPA150SM02-L365F08Y  
datasheet

## Buck Switching Characteristics

figure 30.

FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_r/dt = f(I_C)$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$   $\Omega$

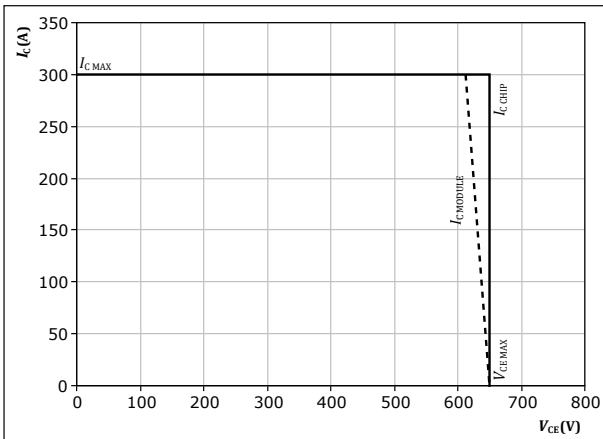
$T_j = 25$  °C  
125 °C  
150 °C

figure 32.

IGBT

Reverse bias safe operating area

$I_C = f(V_{CE})$

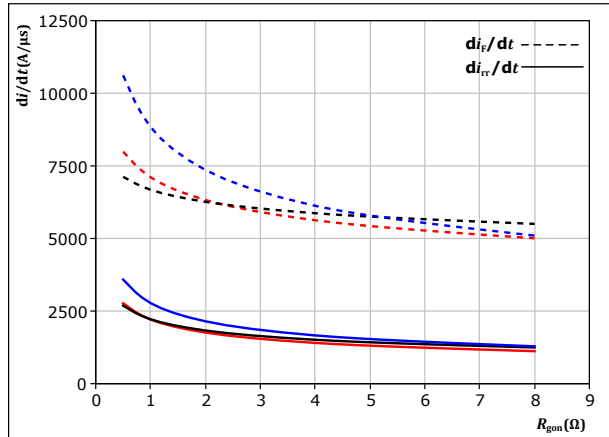


At  $T_j = 150$  °C  
 $R_{gon} = 2$   $\Omega$   
 $R_{goff} = 2$   $\Omega$

figure 31.

FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor  
 $di_f/dt, di_r/dt = f(R_{gon})$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_C = 90$  A

$T_j = 25$  °C  
125 °C  
150 °C





Vincotech

# 10-PY07NPA150SM02-L365F08Y

datasheet

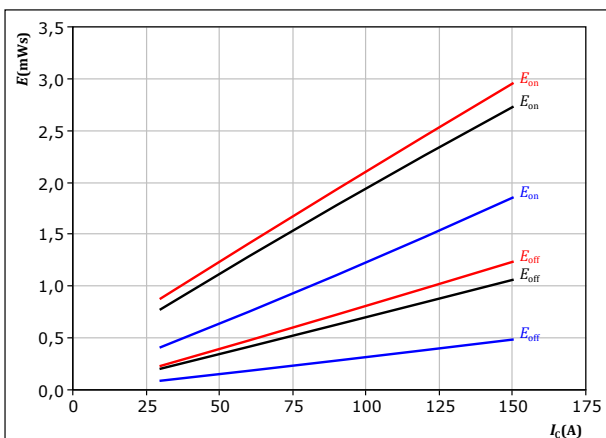
## Boost Switching Characteristics

figure 33.

IGBT

Typical switching energy losses as a function of collector current

$$E = f(I_c)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$   $\Omega$   
 $R_{goff} = 2$   $\Omega$

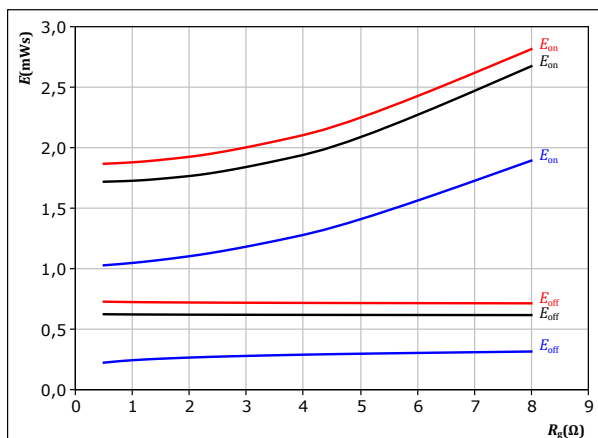
$T_j$ : 25 °C  
125 °C  
150 °C

figure 34.

IGBT

Typical switching energy losses as a function of gate resistor

$$E = f(R_g)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_c = 90$  A

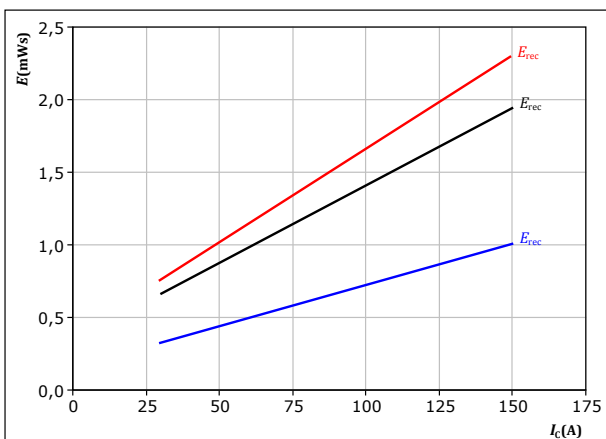
$T_j$ : 25 °C  
125 °C  
150 °C

figure 35.

FWD

Typical reverse recovered energy loss as a function of collector current

$$E_{rec} = f(I_c)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$   $\Omega$

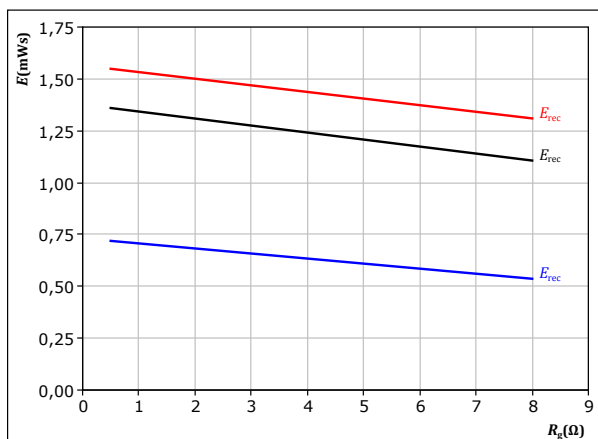
$T_j$ : 25 °C  
125 °C  
150 °C

figure 36.

FWD

Typical reverse recovered energy loss as a function of gate resistor

$$E_{rec} = f(R_g)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_c = 90$  A

$T_j$ : 25 °C  
125 °C  
150 °C



Vincotech

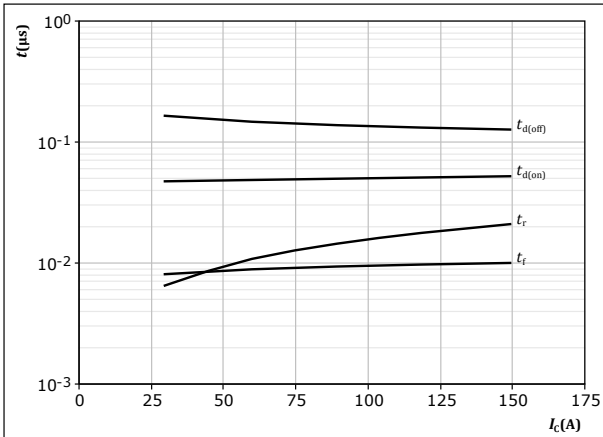
**10-PY07NPA150SM02-L365F08Y**  
datasheet

## Boost Switching Characteristics

figure 37.

IGBT

Typical switching times as a function of collector current  
 $t = f(I_c)$



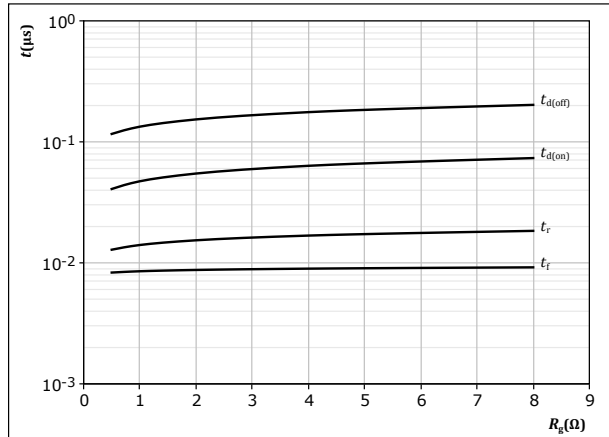
With an inductive load at

$T_j = 150$  °C  
 $V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$  Ω  
 $R_{goff} = 2$  Ω

figure 38.

IGBT

Typical switching times as a function of gate resistor  
 $t = f(R_g)$



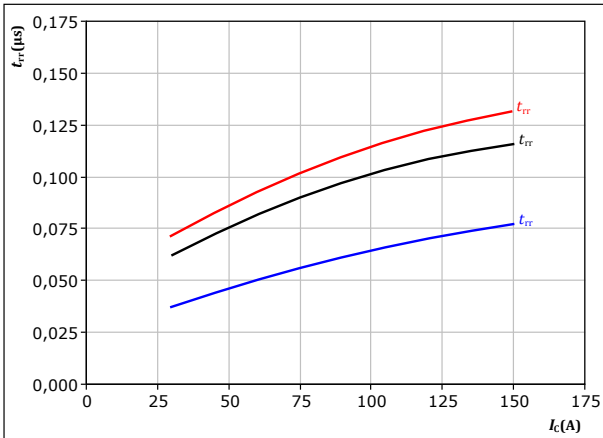
With an inductive load at

$T_j = 150$  °C  
 $V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_c = 90$  A

figure 39.

FWD

Typical reverse recovery time as a function of collector current  
 $t_{rr} = f(I_c)$



With an inductive load at

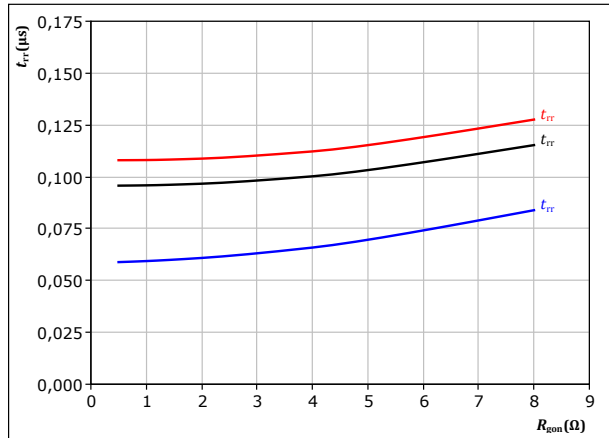
$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$  Ω

$T_j$ : — 25 °C  
— 125 °C  
— 150 °C

figure 40.

FWD

Typical reverse recovery time as a function of IGBT turn on gate resistor  
 $t_{rr} = f(R_{gon})$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_c = 90$  A

$T_j$ : — 25 °C  
— 125 °C  
— 150 °C



Vincotech

10-PY07NPA150SM02-L365F08Y  
datasheet

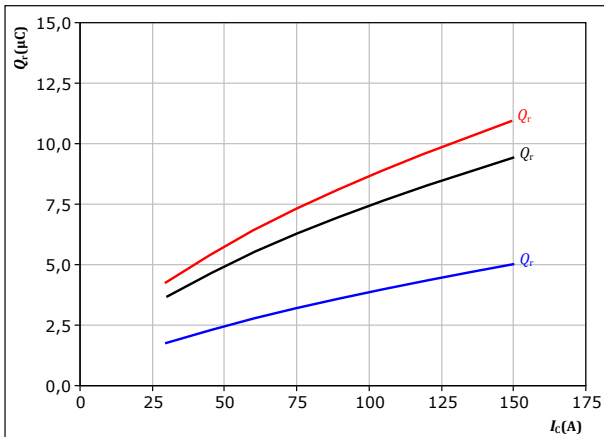
## Boost Switching Characteristics

figure 41.

FWD

Typical recovered charge as a function of collector current

$$Q_r = f(I_c)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$   $\Omega$

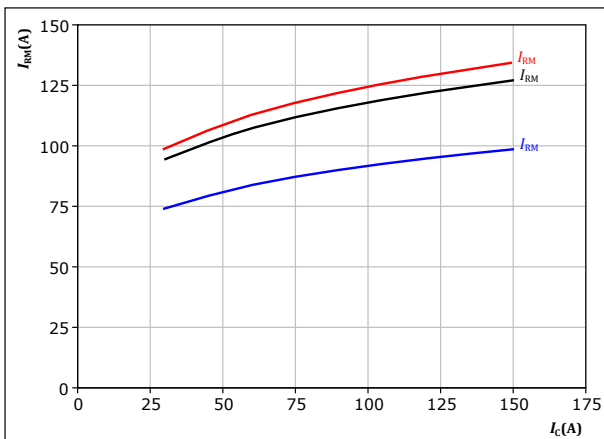
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 43.

FWD

Typical peak reverse recovery current as a function of collector current

$$I_{RM} = f(I_c)$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$   $\Omega$

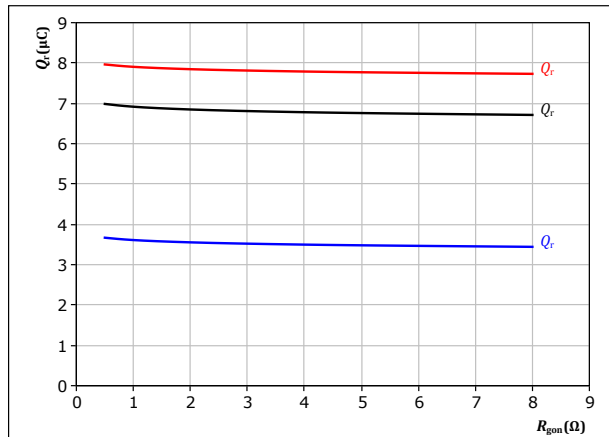
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 42.

FWD

Typical recovered charge as a function of turn on gate resistor

$$Q_r = f(R_{gon})$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_c = 90$  A

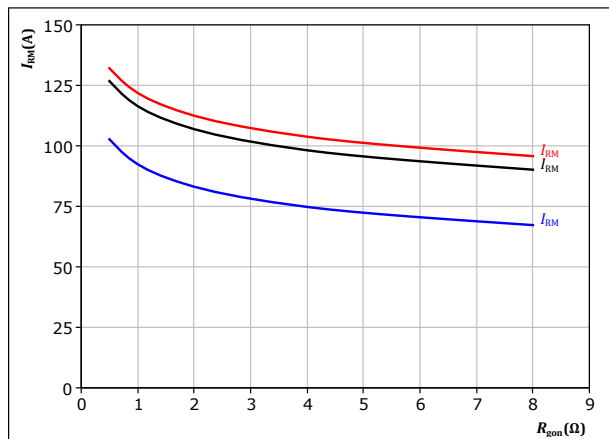
$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C

figure 44.

FWD

Typical peak reverse recovery current as a function of turn on gate resistor

$$I_{RM} = f(R_{gon})$$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_c = 90$  A

$T_j$ :  
— 25 °C  
— 125 °C  
— 150 °C



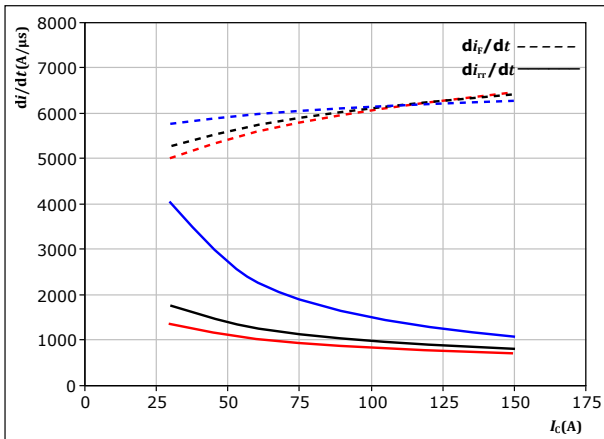
Vincotech

10-PY07NPA150SM02-L365F08Y  
datasheet

## Boost Switching Characteristics

figure 45. FWD

Typical rate of fall of forward and reverse recovery current as a function of collector current  
 $di_f/dt, di_r/dt = f(I_c)$



With an inductive load at

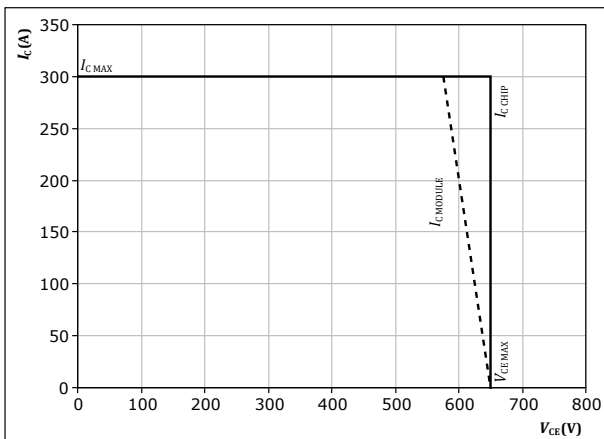
$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $R_{gon} = 2$   $\Omega$

$T_j = 25$  °C  
125 °C  
150 °C

figure 47. IGBT

Reverse bias safe operating area

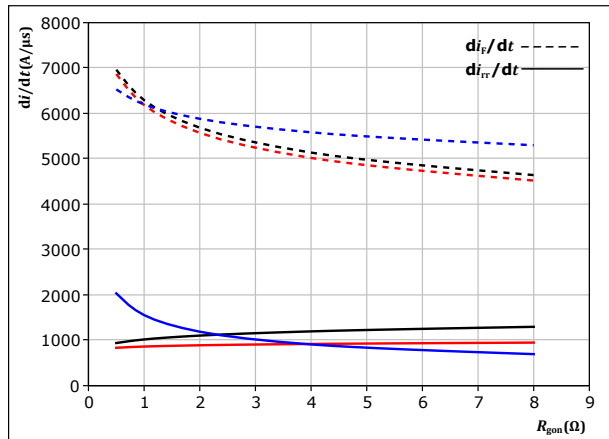
$I_c = f(V_{CE})$



At  $T_j = 150$  °C  
 $R_{gon} = 2$   $\Omega$   
 $R_{goff} = 2$   $\Omega$

figure 46. FWD

Typical rate of fall of forward and reverse recovery current as a function of turn on gate resistor  
 $di_f/dt, di_r/dt = f(R_{gon})$



With an inductive load at

$V_{CE} = 350$  V  
 $V_{GE} = -5/15$  V  
 $I_c = 90$  A

$T_j = 25$  °C  
125 °C  
150 °C



Vincotech

## Switching Definitions

figure 48. IGBT

Turn-off Switching Waveforms & definition of  $t_{doff}$ ,  $t_{Eoff}$  ( $t_{Eoff}$  = integrating time for  $E_{off}$ )

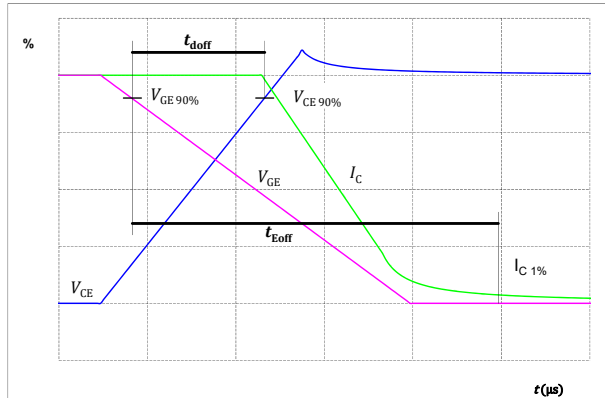


figure 49. IGBT

Turn-on Switching Waveforms & definition of  $t_{don}$ ,  $t_{Eon}$  ( $t_{Eon}$  = integrating time for  $E_{on}$ )

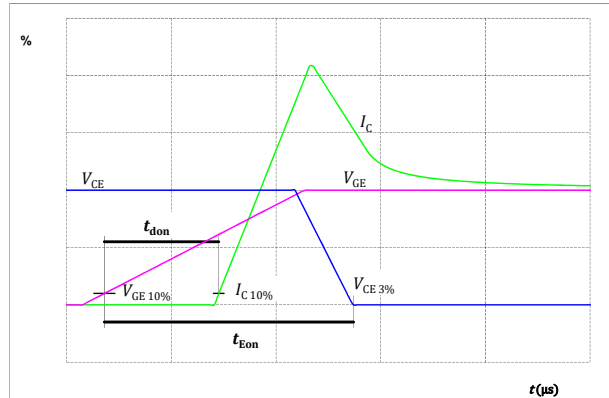


figure 50. IGBT

Turn-off Switching Waveforms & definition of  $t_f$

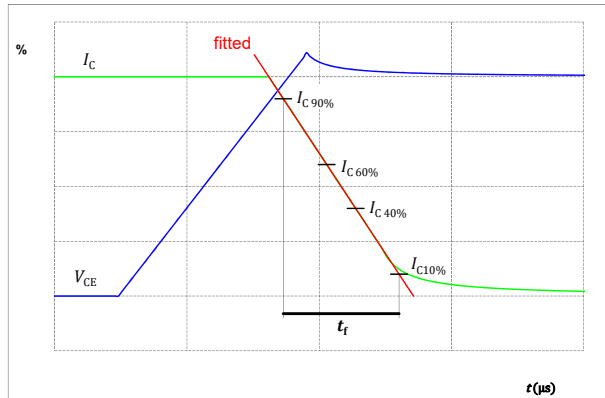
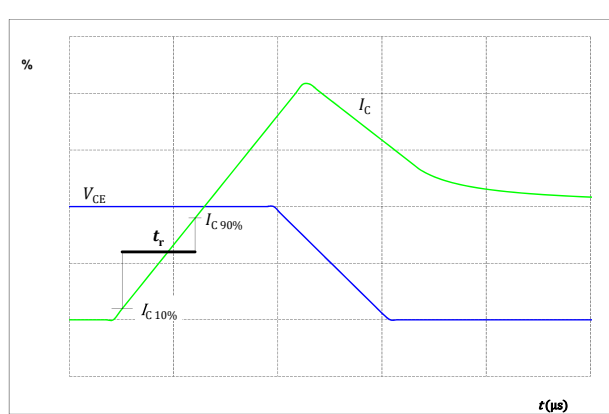


figure 51. IGBT

Turn-on Switching Waveforms & definition of  $t_r$





Vincotech

## Switching Definitions

figure 52.

FWD

Turn-off Switching Waveforms & definition of  $t_{rr}$

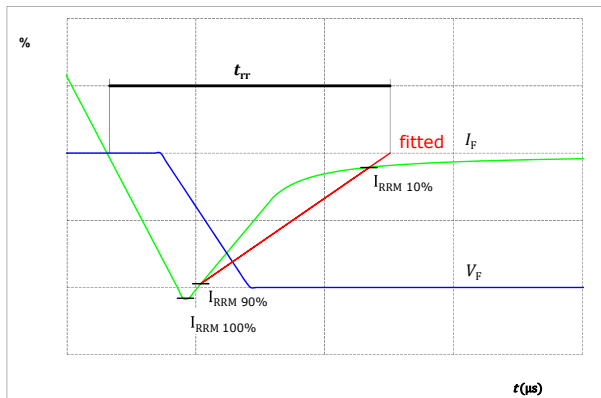
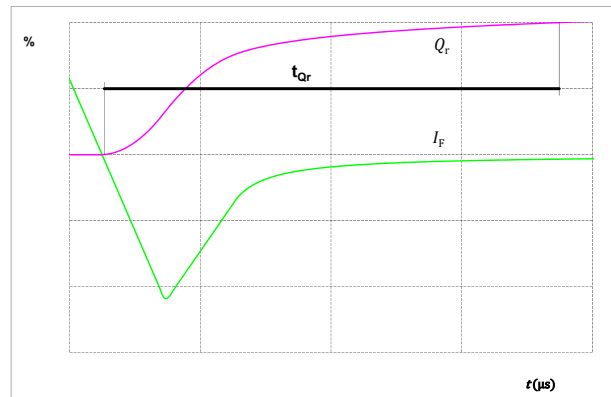


figure 53.

FWD

Turn-on Switching Waveforms & definition of  $t_{Qr}$  ( $t_{Qr}$  = integrating time for  $Q_r$ )





Vincotech

# 10-PY07NPA150SM02-L365F08Y

datasheet

Ordering Code	
Version	Ordering Code
Without thermal paste	10-PY07NPA150SM02-L365F08Y
With thermal paste	10-PY07NPA150SM02-L365F08Y-/3/

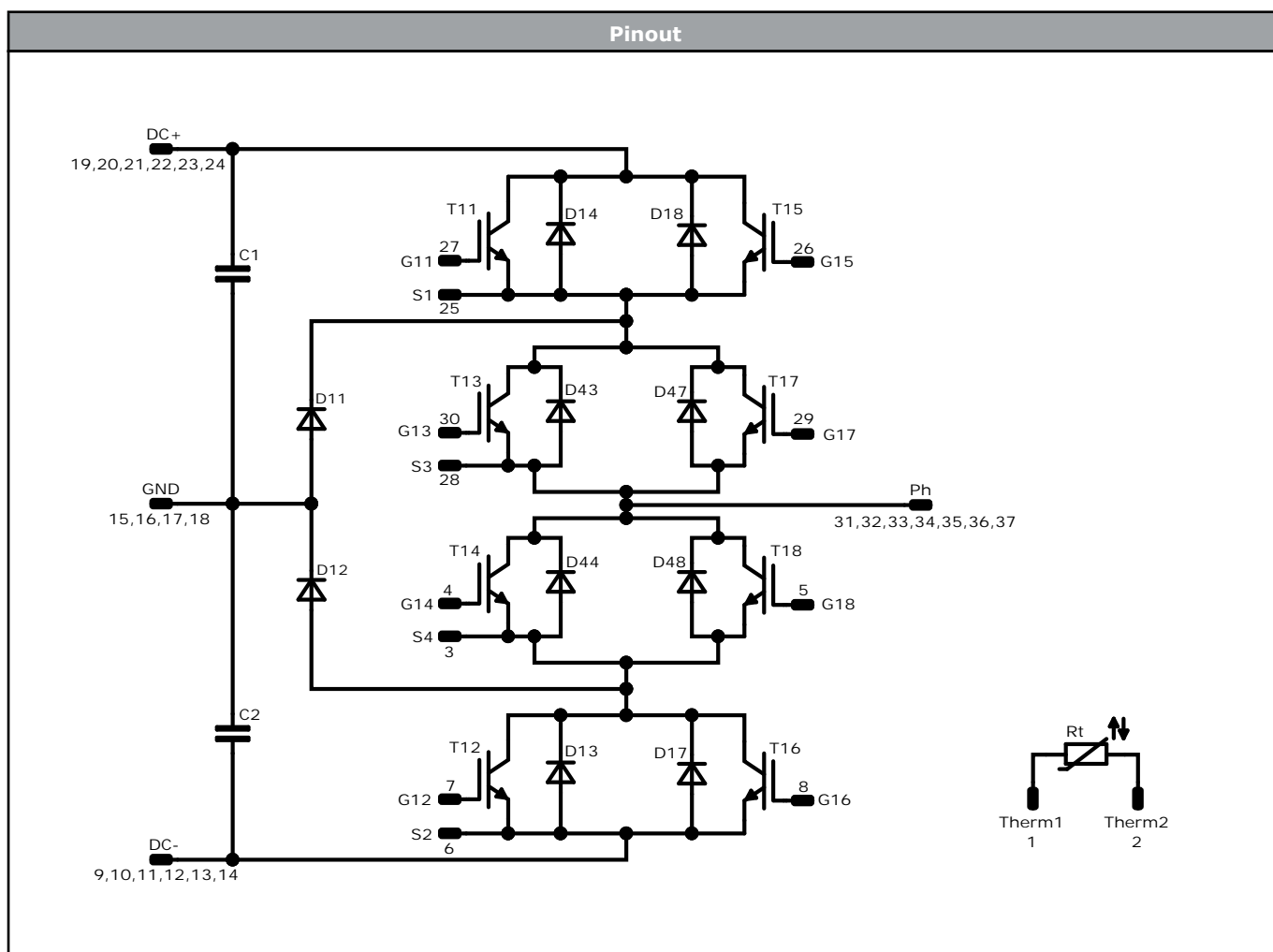
Marking						
	Text	Name	Date code	UL & VIN	Lot	Serial
		NN-NNNNNNNNNNNNNNNNNNNN-TTTTTUVV	WWYY	UL VIN	LLLLL	SSSS
	Datamatrix	Type&Ver TTTTTTVV	Lot number LLLLL	Serial SSSS	Date code WWYY	

Outline																																																																																																																																																											
<p>Pin table [mm]</p> <table><thead><tr><th>Pin</th><th>X</th><th>Y</th><th>Function</th></tr></thead><tbody><tr><td>1</td><td>52,2</td><td>6,9</td><td>Therm1</td></tr><tr><td>2</td><td>52,2</td><td>0</td><td>Therm2</td></tr><tr><td>3</td><td>36,2</td><td>6,75</td><td>S4</td></tr><tr><td>4</td><td>33,2</td><td>7,9</td><td>G14</td></tr><tr><td>5</td><td>33,2</td><td>4,9</td><td>G18</td></tr><tr><td>6</td><td>9,2</td><td>5,75</td><td>S2</td></tr><tr><td>7</td><td>6,2</td><td>6,9</td><td>G12</td></tr><tr><td>8</td><td>6,2</td><td>3,9</td><td>G16</td></tr><tr><td>9</td><td>2,7</td><td>0</td><td>DC-</td></tr><tr><td>10</td><td>0</td><td>0</td><td>DC-</td></tr><tr><td>11</td><td>2,7</td><td>2,7</td><td>DC-</td></tr><tr><td>12</td><td>0</td><td>2,7</td><td>DC-</td></tr><tr><td>13</td><td>2,7</td><td>5,4</td><td>DC-</td></tr><tr><td>14</td><td>0</td><td>5,4</td><td>DC-</td></tr><tr><td>15</td><td>2,7</td><td>12,75</td><td>GND</td></tr><tr><td>16</td><td>0</td><td>12,75</td><td>GND</td></tr><tr><td>17</td><td>2,7</td><td>15,45</td><td>GND</td></tr><tr><td>18</td><td>0</td><td>15,45</td><td>GND</td></tr><tr><td>19</td><td>2,7</td><td>22,8</td><td>DC+</td></tr><tr><td>20</td><td>0</td><td>22,8</td><td>DC+</td></tr><tr><td>21</td><td>2,7</td><td>25,5</td><td>DC+</td></tr><tr><td>22</td><td>0</td><td>25,5</td><td>DC+</td></tr><tr><td>23</td><td>2,7</td><td>28,2</td><td>DC+</td></tr><tr><td>24</td><td>0</td><td>28,2</td><td>DC+</td></tr><tr><td>25</td><td>18,3</td><td>22,45</td><td>S1</td></tr><tr><td>26</td><td>21,3</td><td>21,3</td><td>G15</td></tr><tr><td>27</td><td>21,3</td><td>24,3</td><td>G11</td></tr><tr><td>28</td><td>43</td><td>22,15</td><td>S3</td></tr><tr><td>29</td><td>46</td><td>21</td><td>G17</td></tr><tr><td>30</td><td>46</td><td>24</td><td>G13</td></tr><tr><td>31</td><td>52,2</td><td>20,1</td><td>Ph</td></tr><tr><td>32</td><td>49,5</td><td>22,8</td><td>Ph</td></tr><tr><td>33</td><td>52,2</td><td>22,8</td><td>Ph</td></tr><tr><td>34</td><td>49,5</td><td>25,5</td><td>Ph</td></tr><tr><td>35</td><td>52,2</td><td>25,5</td><td>Ph</td></tr><tr><td>36</td><td>49,5</td><td>28,2</td><td>Ph</td></tr><tr><td>37</td><td>52,2</td><td>28,2</td><td>Ph</td></tr></tbody></table>				Pin	X	Y	Function	1	52,2	6,9	Therm1	2	52,2	0	Therm2	3	36,2	6,75	S4	4	33,2	7,9	G14	5	33,2	4,9	G18	6	9,2	5,75	S2	7	6,2	6,9	G12	8	6,2	3,9	G16	9	2,7	0	DC-	10	0	0	DC-	11	2,7	2,7	DC-	12	0	2,7	DC-	13	2,7	5,4	DC-	14	0	5,4	DC-	15	2,7	12,75	GND	16	0	12,75	GND	17	2,7	15,45	GND	18	0	15,45	GND	19	2,7	22,8	DC+	20	0	22,8	DC+	21	2,7	25,5	DC+	22	0	25,5	DC+	23	2,7	28,2	DC+	24	0	28,2	DC+	25	18,3	22,45	S1	26	21,3	21,3	G15	27	21,3	24,3	G11	28	43	22,15	S3	29	46	21	G17	30	46	24	G13	31	52,2	20,1	Ph	32	49,5	22,8	Ph	33	52,2	22,8	Ph	34	49,5	25,5	Ph	35	52,2	25,5	Ph	36	49,5	28,2	Ph	37	52,2	28,2	Ph
Pin	X	Y	Function																																																																																																																																																								
1	52,2	6,9	Therm1																																																																																																																																																								
2	52,2	0	Therm2																																																																																																																																																								
3	36,2	6,75	S4																																																																																																																																																								
4	33,2	7,9	G14																																																																																																																																																								
5	33,2	4,9	G18																																																																																																																																																								
6	9,2	5,75	S2																																																																																																																																																								
7	6,2	6,9	G12																																																																																																																																																								
8	6,2	3,9	G16																																																																																																																																																								
9	2,7	0	DC-																																																																																																																																																								
10	0	0	DC-																																																																																																																																																								
11	2,7	2,7	DC-																																																																																																																																																								
12	0	2,7	DC-																																																																																																																																																								
13	2,7	5,4	DC-																																																																																																																																																								
14	0	5,4	DC-																																																																																																																																																								
15	2,7	12,75	GND																																																																																																																																																								
16	0	12,75	GND																																																																																																																																																								
17	2,7	15,45	GND																																																																																																																																																								
18	0	15,45	GND																																																																																																																																																								
19	2,7	22,8	DC+																																																																																																																																																								
20	0	22,8	DC+																																																																																																																																																								
21	2,7	25,5	DC+																																																																																																																																																								
22	0	25,5	DC+																																																																																																																																																								
23	2,7	28,2	DC+																																																																																																																																																								
24	0	28,2	DC+																																																																																																																																																								
25	18,3	22,45	S1																																																																																																																																																								
26	21,3	21,3	G15																																																																																																																																																								
27	21,3	24,3	G11																																																																																																																																																								
28	43	22,15	S3																																																																																																																																																								
29	46	21	G17																																																																																																																																																								
30	46	24	G13																																																																																																																																																								
31	52,2	20,1	Ph																																																																																																																																																								
32	49,5	22,8	Ph																																																																																																																																																								
33	52,2	22,8	Ph																																																																																																																																																								
34	49,5	25,5	Ph																																																																																																																																																								
35	52,2	25,5	Ph																																																																																																																																																								
36	49,5	28,2	Ph																																																																																																																																																								
37	52,2	28,2	Ph																																																																																																																																																								



Vincotech

10-PY07NPA150SM02-L365F08Y  
datasheet



Identification					
ID	Component	Voltage	Current	Function	Comment
T11, T15, T12, T16	IGBT	650 V	150 A	Buck Switch	Parallel devices with separate control. Values apply to complete device (T11  T15, T12  T16).
D11, D12	FWD	650 V	150 A	Buck Diode	
T13, T17, T14, T18	IGBT	650 V	150 A	Boost Switch	Parallel devices with separate control. Values apply to complete device (T13  T17, T14  T18).
D13, D17, D14, D18	FWD	650 V	150 A	Boost Diode	Parallel devices. Values apply to complete device (D13  D17, D14  D18).
D44, D48, D43, D47	FWD	650 V	150 A	Boost Sw. Inv. Diode	Parallel devices. Values apply to complete device (D44  D48, D43  D47).
C1, C2	Capacitor	630 V		Capacitor (DC)	
Rt	Thermistor			Thermistor	





Vincotech

**10-PY07NPA150SM02-L365F08Y**  
datasheet

Packaging instruction				
Standard packaging quantity (SPQ) 100	>SPQ	Standard	<SPQ	Sample

Handling instruction
Handling instructions for <i>flow 1</i> packages see vincotech.com website.

Package data
Package data for <i>flow 1</i> packages see vincotech.com website.

Vincotech thermistor reference
See Vincotech thermistor reference table at vincotech.com website.

UL recognition and file number
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.



Document No.:	Date:	Modification:	Pages
10-PY07NPA150SM02-L365F08Y-D8-14	17 Mar. 2021	Correct Vce conditions from 700V to 350V for Buck & Boost Switches and Diodes in all dynamic & switching characteristics	4-7, 17-24

**DISCLAIMER**

The information, specifications, procedures, methods and recommendations herein (together "information") are presented by Vincotech to reader in good faith, are believed to be accurate and reliable, but may well be incomplete and/or not applicable to all conditions or situations that may exist or occur. Vincotech reserves the right to make any changes without further notice to any products to improve reliability, function or design. No representation, guarantee or warranty is made to reader as to the accuracy, reliability or completeness of said information or that the application or use of any of the same will avoid hazards, accidents, losses, damages or injury of any kind to persons or property or that the same will not infringe third parties rights or give desired results. It is reader's sole responsibility to test and determine the suitability of the information and the product for reader's intended use.

**LIFE SUPPORT POLICY**

Vincotech products are not authorised for use as critical components in life support devices or systems without the express written approval of Vincotech.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in labelling can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.